

HIP2123FRTBZ-T

HIP2123FRTBZ-T Information

	HIP2123FRTBZ-T r Renesas Electronics America Integrated Circuits (ICs) PMIC - Gate Drivers IC HALF BRIDGE FET DRIVER 9TDFN 9-WDFN Exposed Pad For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



HIP2123FRTBZ-T Specifications

Manufacturer Part Number	HIP2123FRTBZ-T
Manufacturer	Renesas Electronics America
Category	Integrated Circuits (ICs)
	PMIC - Gate Drivers
Package	9-WDFN Exposed Pad
Series	-
Driven Configuration	Half-Bridge
Channel Type	Independent
Number of Drivers	2
Gate Type	N-Channel MOSFET
Voltage - Supply	8 V ~ 14 V
Logic Voltage - VIL, VIH	1.4V, 2.2V
Current - Peak Output (Source, Sink)	2A, 2A
Input Type	Inverting
High Side Voltage - Max (Bootstrap)	114V
Rise / Fall Time (Typ)	10ns, 10ns
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	9-WDFN Exposed Pad
Supplier Device Package	9-TDFN (4x4)
	Report errors?

HIP2123FRTBZ-T Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

HIP2123FRTBZ-T Payment Methods



HIP2123FRTBZ-T Shipping Methods



If you have any question about HIP2123FRTBZ-T, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com